

Topological Photonic Structures

Ganapathi (Ganesh) Subramania

**Sandia National Laboratories, Albuquerque,
NM**

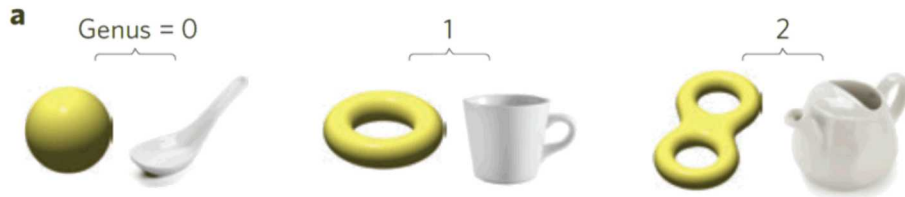
**Collaborators: P. Duke Anderson(Leonardo DRS), Jason Dominguez
(SNL), and Anthony James (SNL),
and Stavroula Foteinopoulou (Univ. of NM)**

**February 16 -19, 2020, The Workshop on Compound
Semiconductor Materials and Devices
Saguaro Palm Springs, Palm Springs CA,USA**

Supported by the Laboratory Directed Research and Development program at Sandia National Laboratories, a multimission laboratory managed and operated by National Technology and Engineering Solutions of Sandia, LLC., a wholly owned subsidiary of Honeywell International, Inc., for the U.S. Department of Energy's National Nuclear Security Administration under contract DE-NA0003525..



Background



Topological invariant : Genus

$$\frac{1}{2\pi} \int_{\text{surface}} \mathcal{K} dA = 2(1 - g)$$

Total Gaussian curvature

Topological Protection: Approaches that exploit topological properties of the phase space of a system can offer stability and robustness to the system of interest from external disturbances. Enables scatter-free, loss-less unidirectional transport.

- Known in electronic systems (QHE)
- Predicted for photonic systems

PHYSICAL REVIEW A 78, 033834 (2008)

Analogs of quantum-Hall-effect edge states in photonic crystals

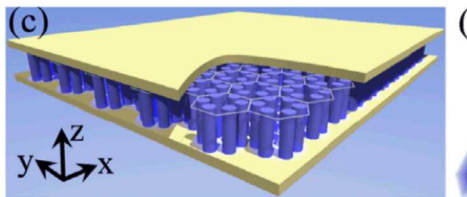
S. Raghu*

Department of Physics, Stanford University, Stanford, California 94305-4045, USA

F. D. M. Haldane

Department of Physics, Princeton University, Princeton, New Jersey 08544-0708, USA

A potential approach ...



PRL 114, 223901 (2015)

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week ending
5 JUNE 2015

Scheme for Achieving a Topological Photonic Crystal by Using Dielectric Material

Long-Hua Wu and Xiao Hu*

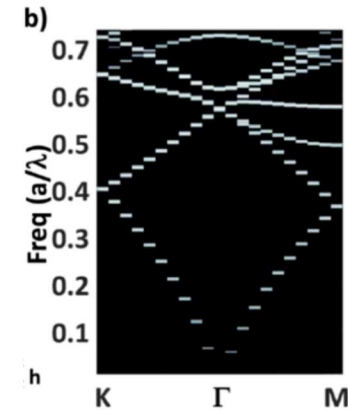
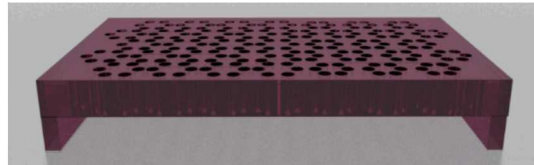
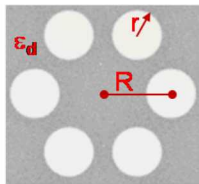
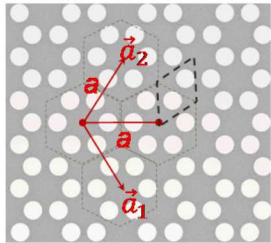
International Center for Materials Nanoarchitectonics (WPI-MANA), National Institute for Materials Science,
Tsukuba 305-0044, Japan

Graduate School of Pure and Applied Sciences, University of Tsukuba, Tsukuba 305-8571, Japan

(Received 10 February 2015; published 3 June 2015)

Approach

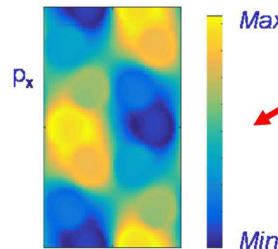
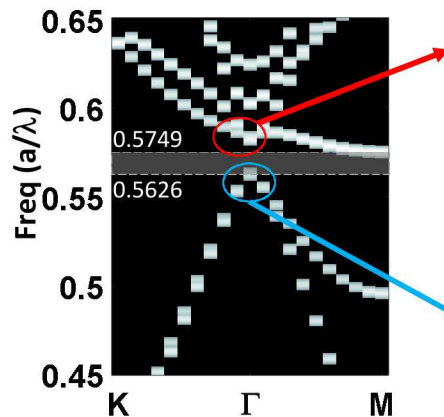
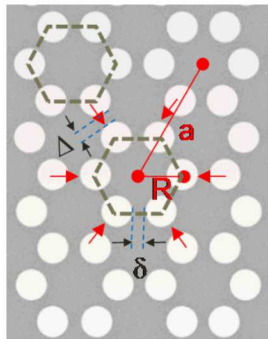
Honeycomb lattice Photonic Crystal (PhC)



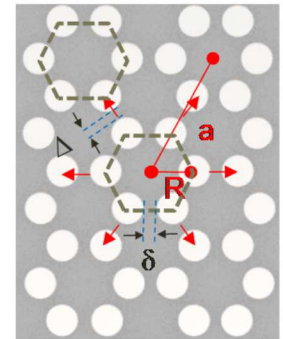
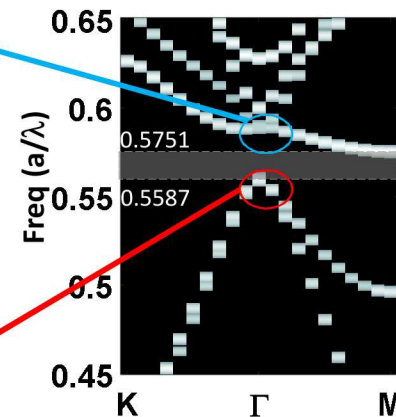
$$a/R = 3.0$$

$$r = 0.13a$$

Compressed lattice $a/R = 3.1$
Topologically Trivial PhC



Expanded lattice $a/R = 2.9$
Topologically non-Trivial PhC

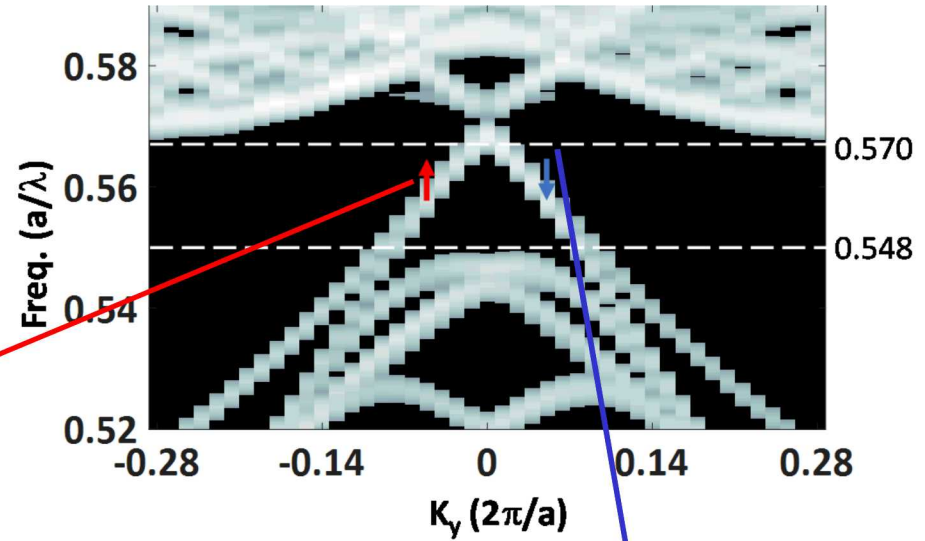
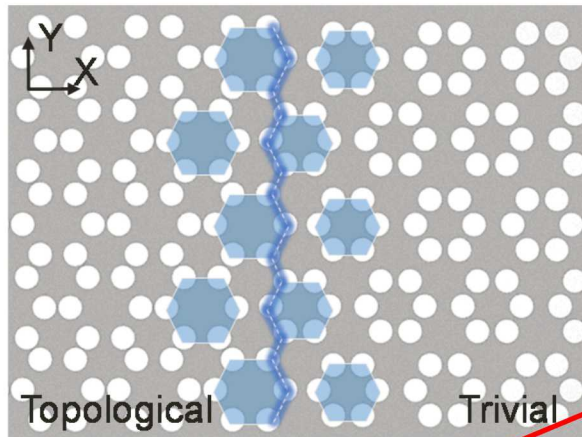


$$\Delta = a - 2(R + r)$$

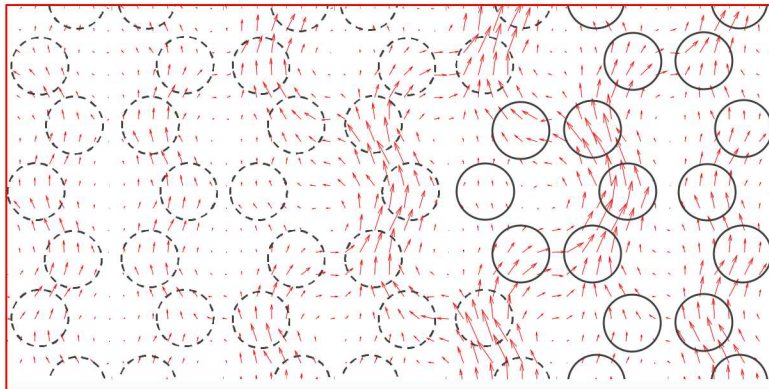
$$\delta = R - 2r$$

Unidirectional Edge State Propagation

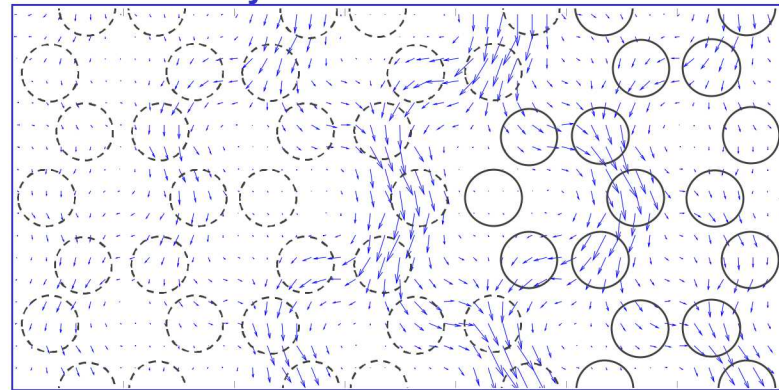
Zig-zag interface



$k_y = -0.05(2\pi/a)$

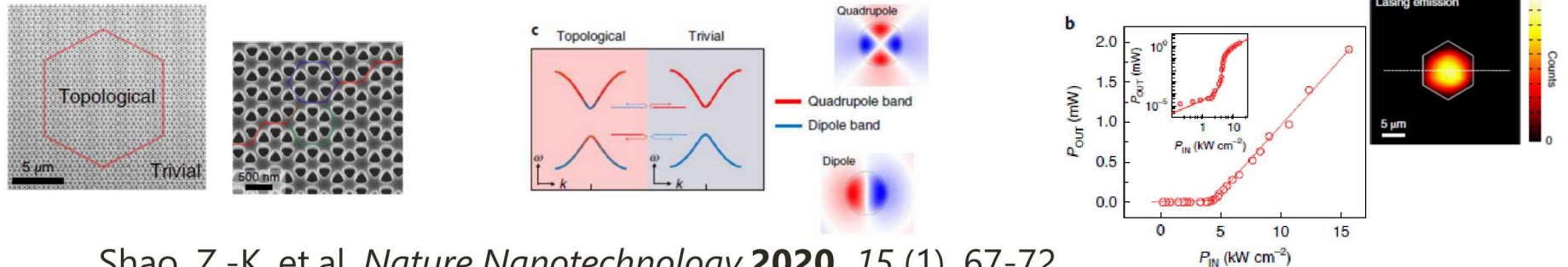


$k_y = 0.05(2\pi/a)$



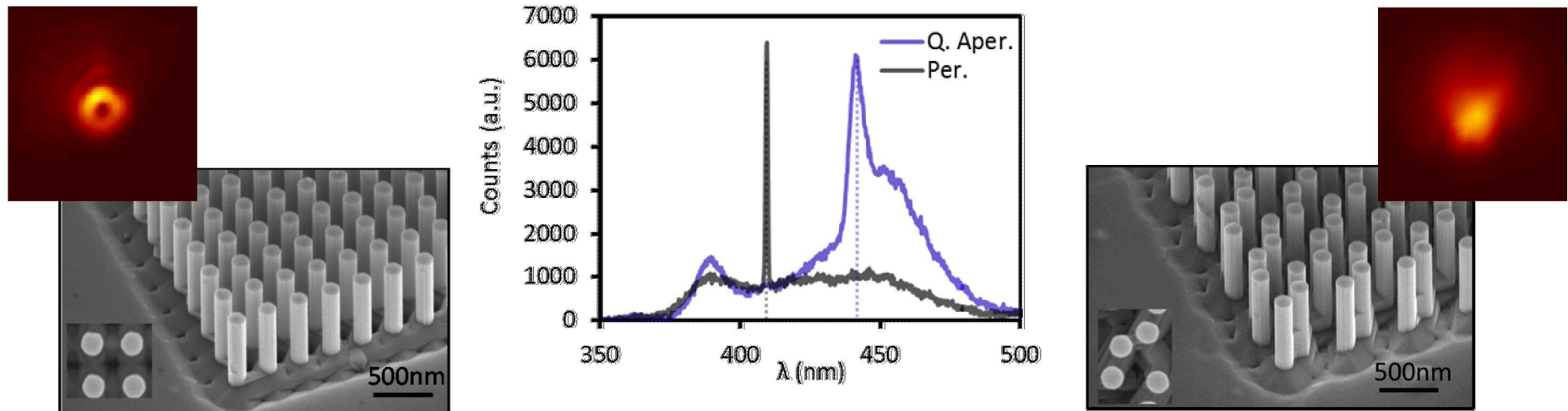
Experimental Structures

Lasing in Topological PhC structure with InGaAsP MWQ/ InP



Shao, Z.-K. et.al. *Nature Nanotechnology* **2020**, 15 (1), 67-72.

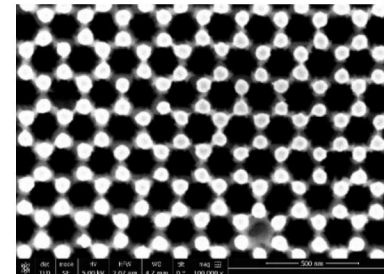
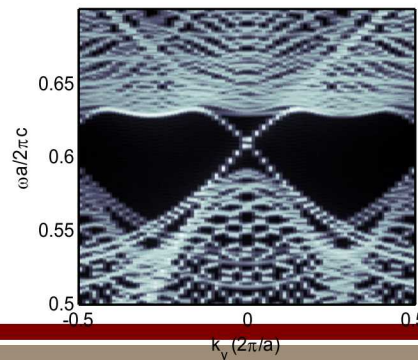
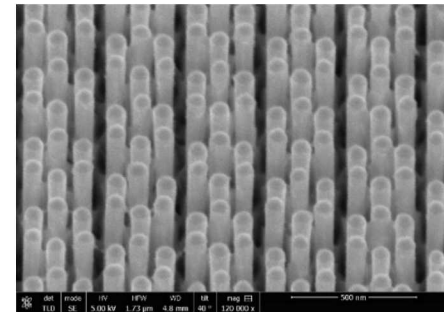
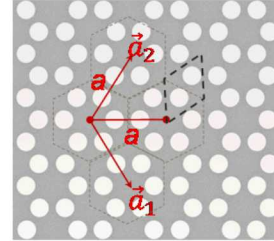
Opportunities in InGaN MQW/GaN system



P. D Anderson, et. al. *Optical Materials Express*, **7**, 3634(2017).

J.B. Wright, et. al. *Sci. Rep.*, **3**, 2982 (2013).

- Topologically protected structures in photonics
- Interface photonics states at the topological /trivial interface
 - Unidirectional propagation of helical states
- Novel photonic cavity design for lasers
- Implementation for lasing in III-nitride rods



Thank you for your attention!

Extras ...

Topological Photonics Research Activities

PHYSICAL REVIEW A 78, 033834 (2008)

Analog of quantum-Hall-effect edge states in photonic crystals

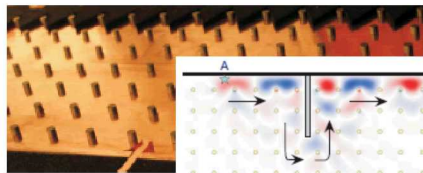
S. Raghu*

Department of Physics, Stanford University, Stanford, California 94305-4045, USA

F. D. M. Haldane

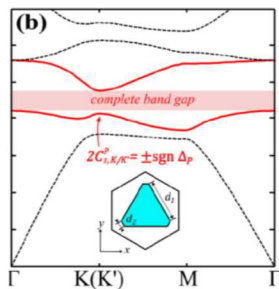
Department of Physics, Princeton University, Princeton, New Jersey 08544-0708, USA

One-way transport at microwave frequency



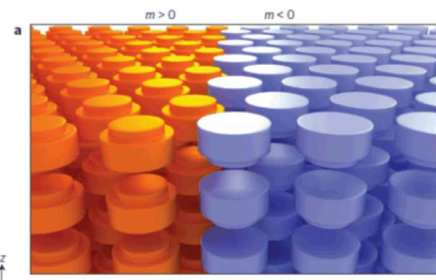
Z. Wang, Y. Chong, et.al. ,
Nature **461**, 772 (2009).

Valley hall PTI



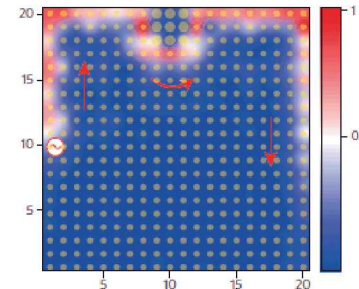
M. Tzuhuan and S. Gennady,
NJP.**18** (2), 025012 (2016).

3D All dielectric PTI



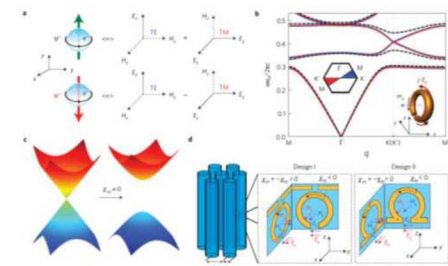
A. Slobozhanyuk, et.al. , Nat
Photon **11** (2), 130-136 (2017).

One-way edge transport



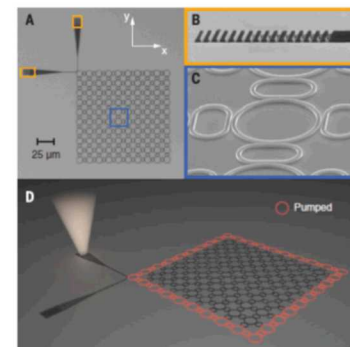
K.Fang, Z. Yu , S.H.Fan ,
Nat. Phot. **6** , (2012)

Metamaterial PTI



A. B. Khanikaev et.al. Nat
Mater **12** (3), 233-239 (2013).

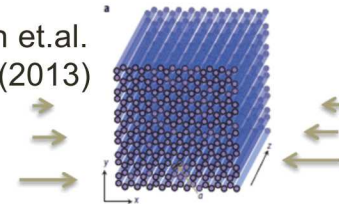
PTI lasing



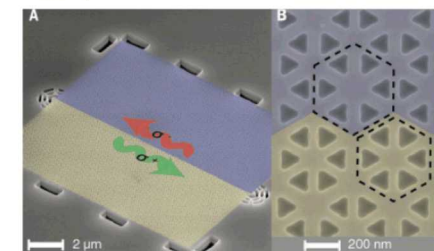
Bandres, M. A. et al. Science
359, eaar1231 (2018).

Strain induced pseud mag. field in optical fiber arrays

M.Rechtsman et.al.
Nat. Phot. **7** (2013)



Topological edge states in III-V



Barik, S. et al.. Science
359, 666 (2018).

Topological Photonics Spin Hall in Dielectric PC

PRL 114, 223901 (2015)

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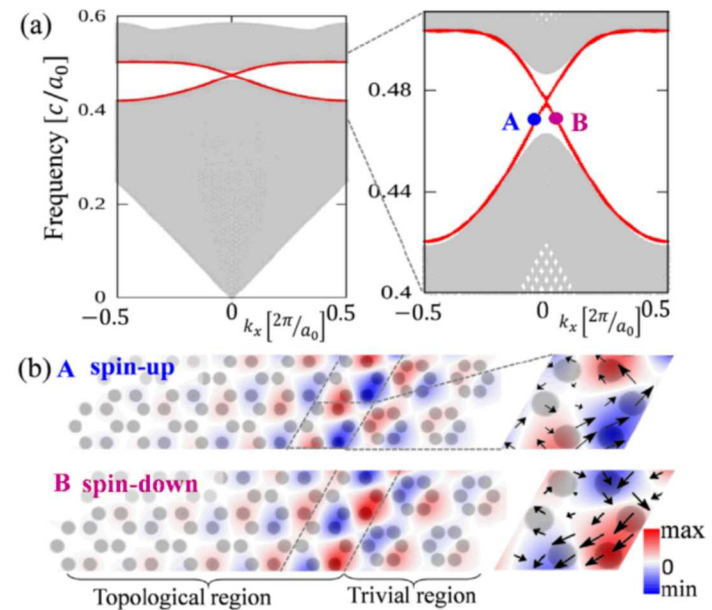
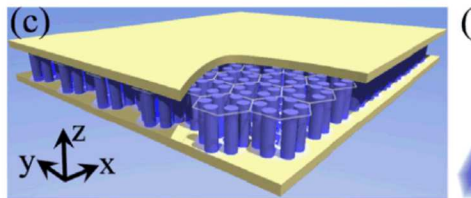
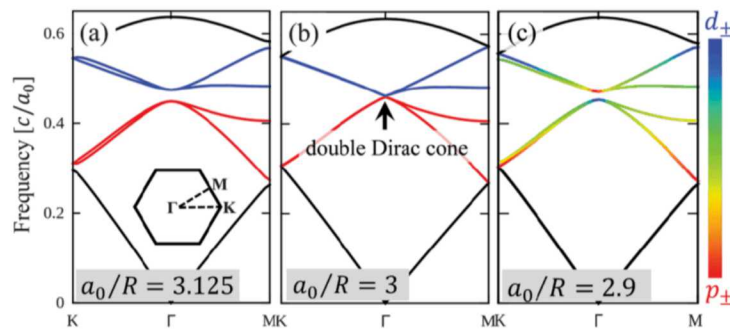
Scheme for Achieving a Topological Photonic Crystal by Using Dielectric Material

Long-Hua Wu and Xiao Hu*

*International Center for Materials Nanoarchitectonics (WPI-MANA), National Institute for Materials Science,
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Graduate School of Pure and Applied Sciences, University of Tsukuba, Tsukuba 305-8571, Japan

(Received 10 February 2015; published 3 June 2015)



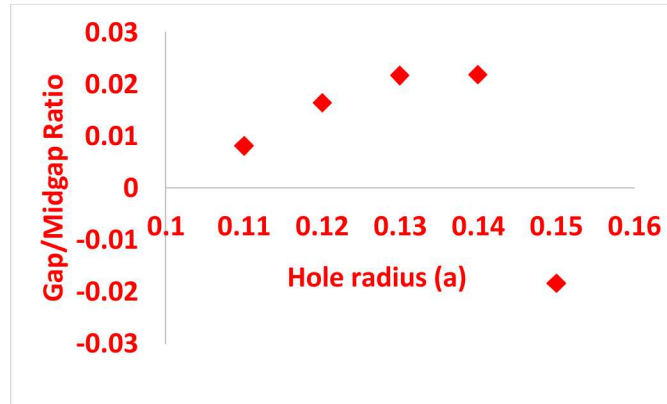
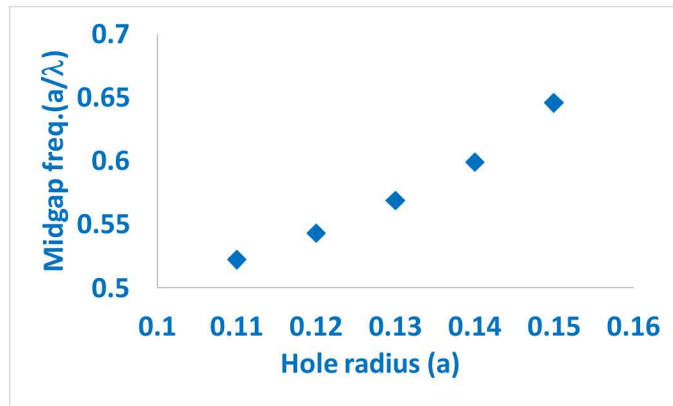
Modified honeycomb lattice of hexagonal cylindrical dielectric rods

Circular Hole Array Honeycomb Lattice Photonic Crystal

Hole radius 'r' dependence

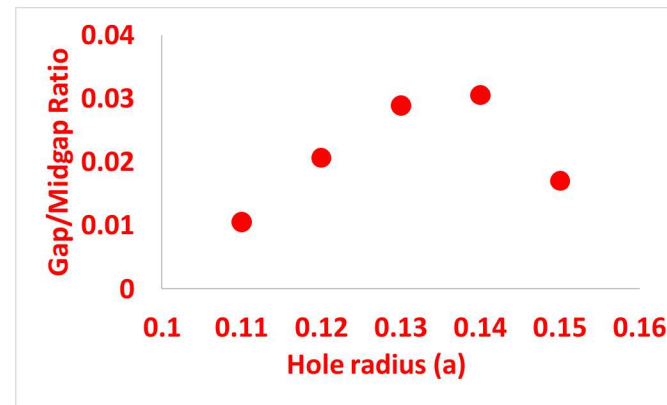
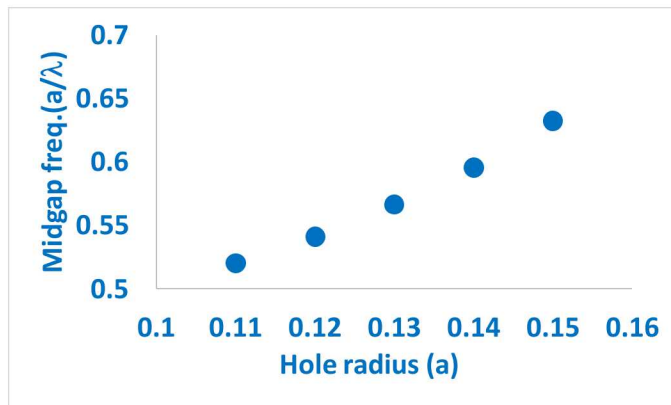
Compressed $a/R = 3.1$

Membrane thickness
'h' = $0.25a$



At $\lambda \sim 1500\text{nm}$
 $\Delta\lambda \sim 30\text{nm}$

Expanded $a/R = 2.9$



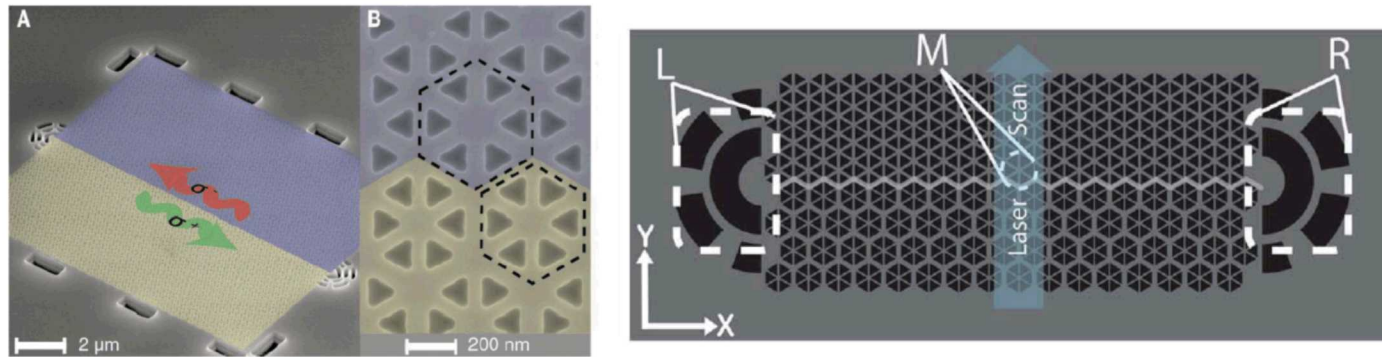
At $\lambda \sim 1500\text{nm}$
 $\Delta\lambda \sim 45\text{nm}$

Reasonable operational bandwidth possible at the telecom frequencies

How to launch a helical source?

Quantum Dot based Helical Sources

Barik, S., et al. (2018). "A topological quantum optics interface." Science **359**(6376): 666.



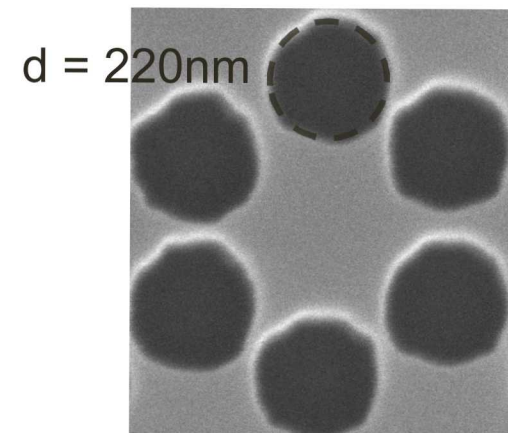
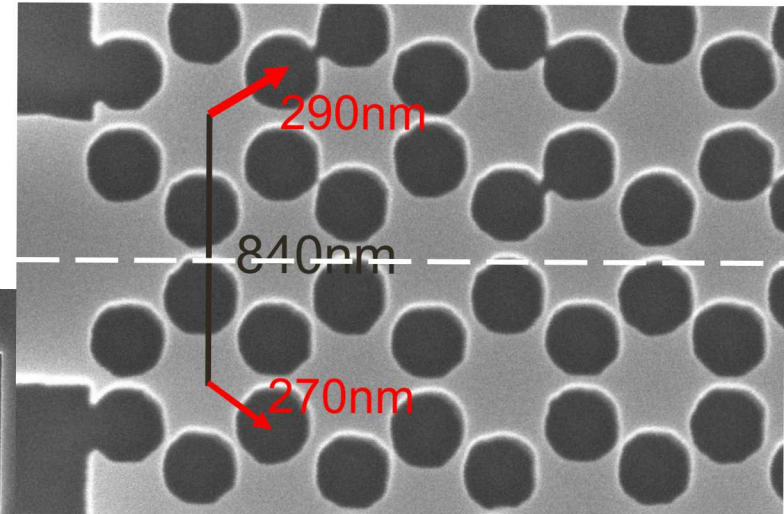
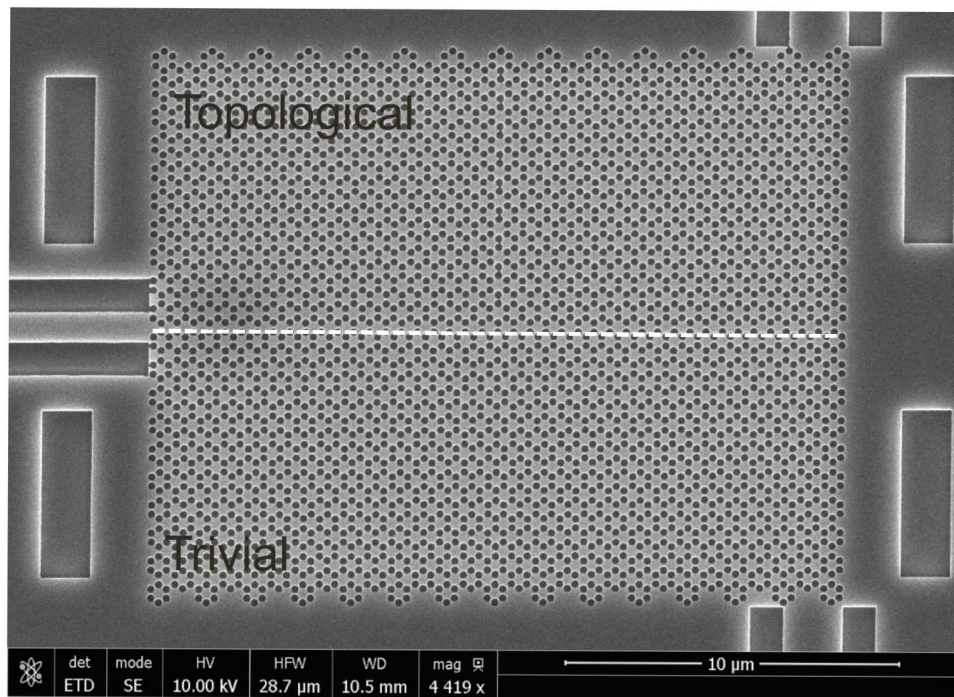
- Create a quantum dot inside the structure
- Apply high B field to split energy level as well as helicity
- Unidirectional propagation of single photon source
- Bandwidth difficult to demonstrate

What about a passive structure to manipulate light incident from elsewhere?

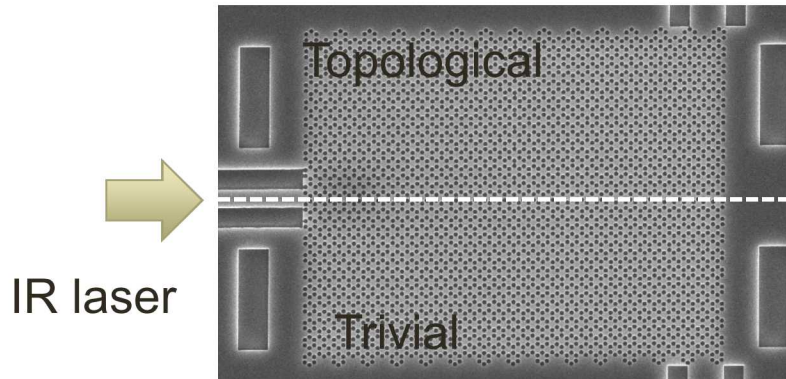
Fabrication on Silicon on Insulator (SOI) - Membrane

Pattern transfer to Si

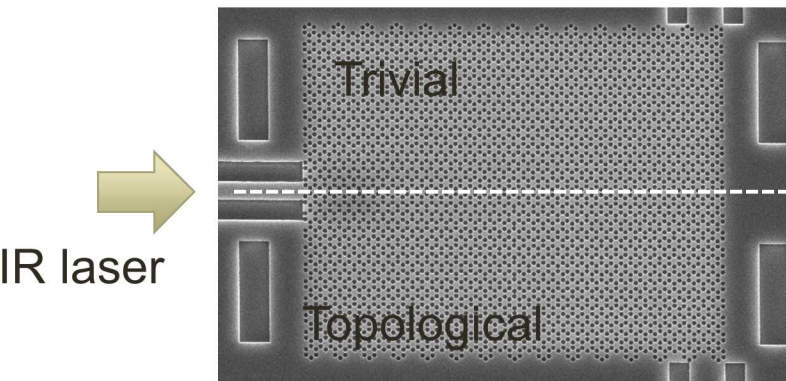
- ~ 50 nm SiO₂ is used as hardmask for pattern transfer
- Highly selective HBr based RIE for Si etch



Optical Measurement

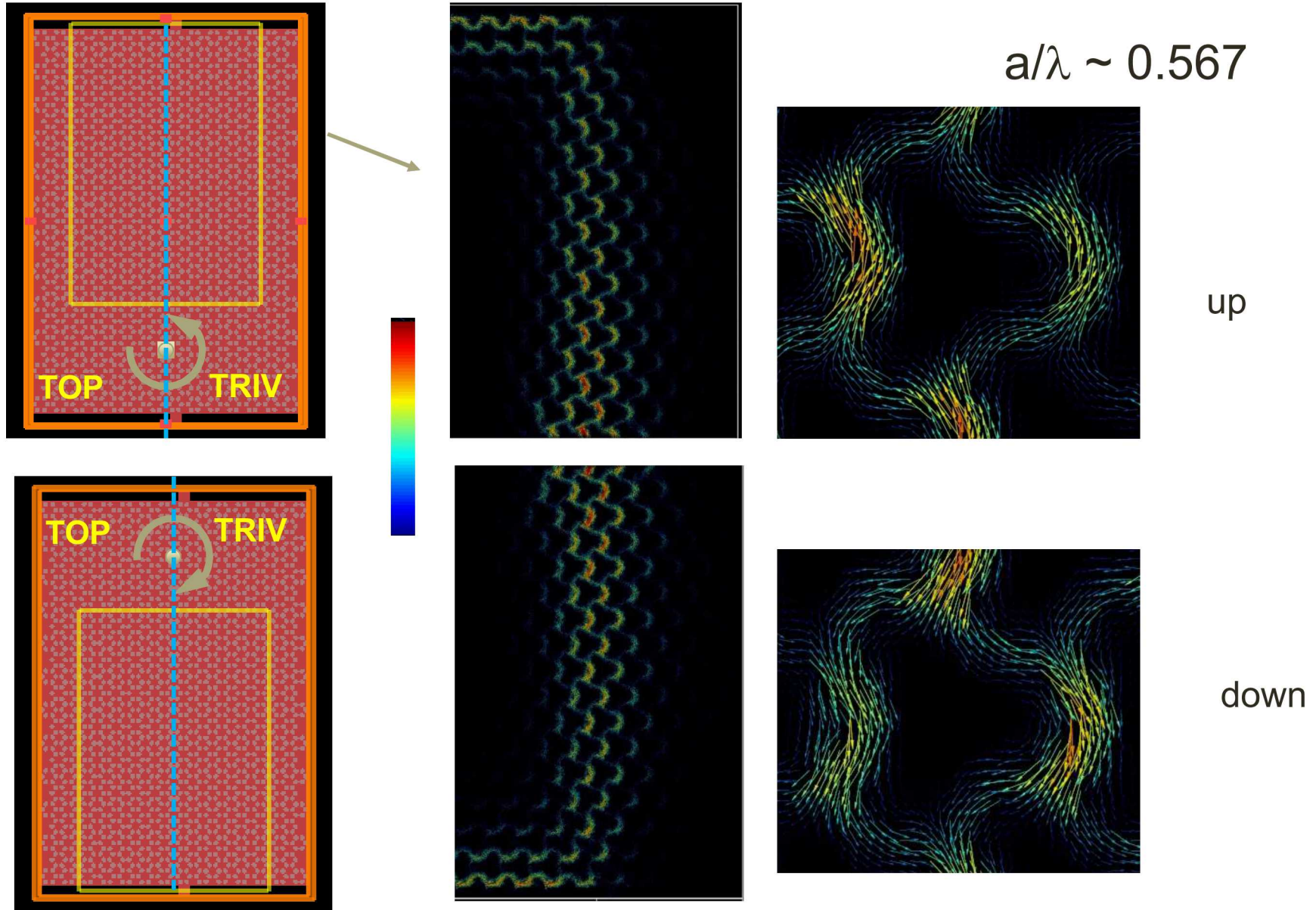


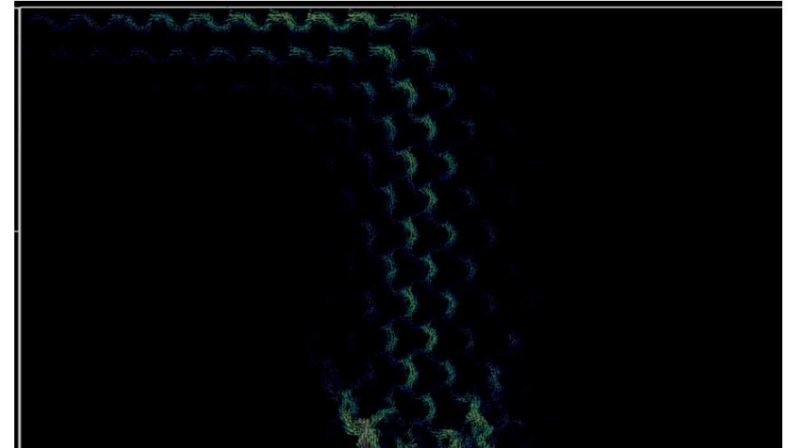
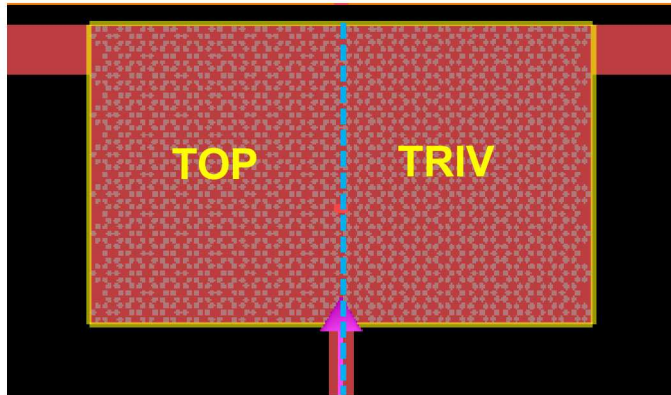
$\lambda \sim 1536\text{nm}$



- Light propagation shows clear distinction based on orientation of the Topological PhC relative to the Trivial PhC
- In progress ...

Unidirectional Propagation with Helical Sources





High index trivial medium

